

# **isc Silicon NPN Power Transistor**

#### **DESCRIPTION**

- · DC Current Gain-
- : h<sub>FE</sub>= 40-250(Min)@ I<sub>C</sub>= 0.15A
- · Collector-Emitter Sustaining Voltage -
  - : V<sub>CEO(SUS)</sub>= 80V(Min)
- Complement to type BD180
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **APPLICATIONS**



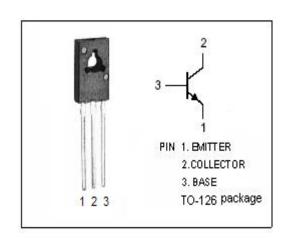
 Designed for medium power linear and switching applications.

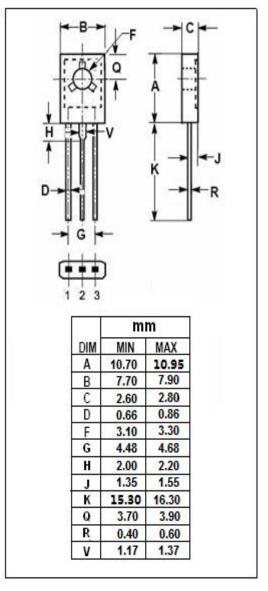
## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	80	V
V <sub>CEO</sub>	Collector-Emitter Voltage	80	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current-Continuous	3	А
Ісм	Collector Current-Pulse	7	А
Pc	Collector Power Dissipation @ T <sub>C</sub> =25 °C	30	W
TJ	T <sub>J</sub> Junction Temperature		$^{\circ}$ C
T <sub>stg</sub>	T <sub>stg</sub> Storage Temperature Range		$^{\circ}$

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance,Junction to Case	8.5	°C/W
R <sub>th j-a</sub>	th j-a Thermal Resistance, Junction to Ambient		°C/W







## isc Silicon NPN Power Transistor

**BD179** 

#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 50mA ; I <sub>B</sub> = 0	80			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1A; I <sub>B</sub> = 0.1A			0.8	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 1A; V <sub>CE</sub> = 2V			1.3	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 80V; I <sub>E</sub> = 0			100	μА
ІЕВО	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			1	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 150mA; V <sub>CE</sub> = 2V	40		250	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 2V	15			
fτ	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.25A; V <sub>CE</sub> = 10V	3			MHz

# h<sub>FE-1</sub> Classifications

6	10	16
40-100	63-160	100-250

## **NOTICE:**

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